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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded - Microcontrollers</u>"

Details	
Product Status	Active
Core Processor	CIP-51 8051
Core Size	8-Bit
Speed	25MHz
Connectivity	I <sup>2</sup> C, SMBus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	16
Program Memory Size	4KB (4K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	512 x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 3.6V
Data Converters	A/D 15x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	20-WFQFN Exposed Pad
Supplier Device Package	20-QFN (3x3)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm8bb10f4i-a-qfn20

Ordering Part Number	Flash Memory (kB)	RAM (Bytes)	Digital Port I/Os (Total)	ADC0 Channels	Comparator 0 Inputs	Comparator 1 Inputs	Pb-free (RoHS Compliant)	Temperature Range	Package
EFM8BB10F8I-A-QFN20	8	512	16	15	8	7	Yes	-40 to +125 C	QFN20
EFM8BB10F8I-A-SOIC16	8	512	13	12	6	6	Yes	-40 to +125 C	SOIC16
EFM8BB10F4I-A-QFN20	4	512	16	15	8	7	Yes	-40 to +125 C	QFN20
EFM8BB10F2I-A-QFN20	2	256	16	15	8	7	Yes	-40 to +125 C	QFN20
EFM8BB10F8A-A-QFN20	8	512	16	15	8	7	Yes	-40 to +125 C	QFN20
EFM8BB10F4A-A-QFN20	4	512	16	15	8	7	Yes	-40 to +125 C	QFN20
EFM8BB10F2A-A-QFN20	2	256	16	15	8	7	Yes	-40 to +125 C	QFN20

The A-grade (i.e. EFM8BB10F8A-A-QFN20) devices receive full automotive quality production status, including AEC-Q100 qualification, registration with International Material Data System (IMDS), and Part Production Approval Process (PPAP) documentation. PPAP documentation is available at <a href="https://www.silabs.com">www.silabs.com</a> with a registered and NDA approved user account.

# 3. System Overview

### 3.1 Introduction

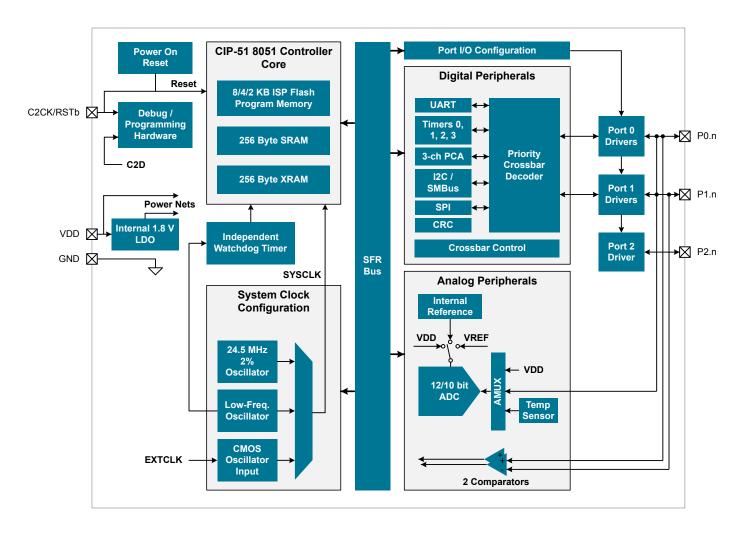


Figure 3.1. Detailed EFM8BB1 Block Diagram

This section describes the EFM8BB1 family at a high level. For more information on each module including register definitions, see the EFM8BB1 Reference Manual.

### 3.2 Power

All internal circuitry draws power from the VDD supply pin. External I/O pins are powered from the VIO supply voltage (or VDD on devices without a separate VIO connection), while most of the internal circuitry is supplied by an on-chip LDO regulator. Control over the device power can be achieved by enabling/disabling individual peripherals as needed. Each analog peripheral can be disabled when not in use and placed in low power mode. Digital peripherals, such as timers and serial buses, have their clocks gated off and draw little power when they are not in use.

Table 3.1. Power Modes

Power Mode	Details	Mode Entry	Wake-Up Sources
Normal	Core and all peripherals clocked and fully operational	_	_
Idle	<ul><li>Core halted</li><li>All peripherals clocked and fully operational</li><li>Code resumes execution on wake event</li></ul>	Set IDLE bit in PCON0	Any interrupt
Stop	<ul><li>All internal power nets shut down</li><li>Pins retain state</li><li>Exit on any reset source</li></ul>	1. Clear STOPCF bit in REG0CN 2. Set STOP bit in PCON0	Any reset source
Shutdown	<ul><li>All internal power nets shut down</li><li>Pins retain state</li><li>Exit on pin or power-on reset</li></ul>	1. Set STOPCF bit in REG0CN 2. Set STOP bit in PCON0	RSTb pin reset     Power-on reset

### 3.3 I/O

Digital and analog resources are externally available on the device's multi-purpose I/O pins. Port pins P0.0-P1.7 can be defined as general-purpose I/O (GPIO), assigned to one of the internal digital resources through the crossbar or dedicated channels, or assigned to an analog function. Port pins P2.0 and P2.1 can be used as GPIO. Additionally, the C2 Interface Data signal (C2D) is shared with P2.0.

- Up to 18 multi-functions I/O pins, supporting digital and analog functions.
- Flexible priority crossbar decoder for digital peripheral assignment.
- · Two drive strength settings for each port.
- Two direct-pin interrupt sources with dedicated interrupt vectors (INT0 and INT1).
- Up to 16 direct-pin interrupt sources with shared interrupt vector (Port Match).

## 3.4 Clocking

The CPU core and peripheral subsystem may be clocked by both internal and external oscillator resources. By default, the system clock comes up running from the 24.5 MHz oscillator divided by 8.

- · Provides clock to core and peripherals.
- 24.5 MHz internal oscillator (HFOSC0), accurate to ±2% over supply and temperature corners.
- 80 kHz low-frequency oscillator (LFOSC0).
- External CMOS clock input (EXTCLK).
- Clock divider with eight settings for flexible clock scaling: Divide the selected clock source by 1, 2, 4, 8, 16, 32, 64, or 128.

#### 3.5 Counters/Timers and PWM

#### **Programmable Counter Array (PCA0)**

The programmable counter array (PCA) provides multiple channels of enhanced timer and PWM functionality while requiring less CPU intervention than standard counter/timers. The PCA consists of a dedicated 16-bit counter/timer and one 16-bit capture/compare module for each channel. The counter/timer is driven by a programmable timebase that has flexible external and internal clocking options. Each capture/compare module may be configured to operate independently in one of five modes: Edge-Triggered Capture, Software Timer, High-Speed Output, Frequency Output, or Pulse-Width Modulated (PWM) Output. Each capture/compare module has its own associated I/O line (CEXn) which is routed through the crossbar to port I/O when enabled.

- · 16-bit time base
- · Programmable clock divisor and clock source selection
- · Up to three independently-configurable channels
- 8, 9, 10, 11 and 16-bit PWM modes (center or edge-aligned operation)
- · Output polarity control
- · Frequency output mode
- · Capture on rising, falling or any edge
- · Compare function for arbitrary waveform generation
- · Software timer (internal compare) mode
- · Can accept hardware "kill" signal from comparator 0

### Timers (Timer 0, Timer 1, Timer 2, and Timer 3)

Several counter/timers are included in the device: two are 16-bit counter/timers compatible with those found in the standard 8051, and the rest are 16-bit auto-reload timers for timing peripherals or for general purpose use. These timers can be used to measure time intervals, count external events and generate periodic interrupt requests. Timer 0 and Timer 1 are nearly identical and have four primary modes of operation. The other timers offer both 16-bit and split 8-bit timer functionality with auto-reload and capture capabilities.

Timer 0 and Timer 1 include the following features:

- Standard 8051 timers, supporting backwards-compatibility with firmware and hardware.
- · Clock sources include SYSCLK, SYSCLK divided by 12, 4, or 48, the External Clock divided by 8, or an external pin.
- · 8-bit auto-reload counter/timer mode
- · 13-bit counter/timer mode
- · 16-bit counter/timer mode
- · Dual 8-bit counter/timer mode (Timer 0)

Timer 2 and Timer 3 are 16-bit timers including the following features:

- Clock sources include SYSCLK, SYSCLK divided by 12, or the External Clock divided by 8.
- · 16-bit auto-reload timer mode
- · Dual 8-bit auto-reload timer mode
- External pin capture (Timer 2)
- · LFOSC0 capture (Timer 3)

### Watchdog Timer (WDT0)

The device includes a programmable watchdog timer (WDT) running off the low-frequency oscillator. A WDT overflow forces the MCU into the reset state. To prevent the reset, the WDT must be restarted by application software before overflow. If the system experiences a software or hardware malfunction preventing the software from restarting the WDT, the WDT overflows and causes a reset. Following a reset, the WDT is automatically enabled and running with the default maximum time interval. If needed, the WDT can be disabled by system software or locked on to prevent accidental disabling. Once locked, the WDT cannot be disabled until the next system reset. The state of the RST pin is unaffected by this reset.

The Watchdog Timer has the following features:

- · Programmable timeout interval
- · Runs from the low-frequency oscillator
- · Lock-out feature to prevent any modification until a system reset

## 3.6 Communications and Other Digital Peripherals

#### Universal Asynchronous Receiver/Transmitter (UART0)

UART0 is an asynchronous, full duplex serial port offering modes 1 and 3 of the standard 8051 UART. Enhanced baud rate support allows a wide range of clock sources to generate standard baud rates. Received data buffering allows UART0 to start reception of a second incoming data byte before software has finished reading the previous data byte.

The UART module provides the following features:

- · Asynchronous transmissions and receptions.
- Baud rates up to SYSCLK/2 (transmit) or SYSCLK/8 (receive).
- · 8- or 9-bit data.
- · Automatic start and stop generation.
- Single-byte FIFO on transmit and receive.

### Serial Peripheral Interface (SPI0)

The serial peripheral interface (SPI) module provides access to a flexible, full-duplex synchronous serial bus. The SPI can operate as a master or slave device in both 3-wire or 4-wire modes, and supports multiple masters and slaves on a single SPI bus. The slave-select (NSS) signal can be configured as an input to select the SPI in slave mode, or to disable master mode operation in a multi-master environment, avoiding contention on the SPI bus when more than one master attempts simultaneous data transfers. NSS can also be configured as a firmware-controlled chip-select output in master mode, or disabled to reduce the number of pins required. Additional general purpose port I/O pins can be used to select multiple slave devices in master mode.

The SPI module includes the following features:

- Supports 3- or 4-wire operation in master or slave modes.
- Supports external clock frequencies up to SYSCLK / 2 in master mode and SYSCLK / 10 in slave mode.
- · Support for four clock phase and polarity options.
- · 8-bit dedicated clock clock rate generator.
- · Support for multiple masters on the same data lines.

## System Management Bus / I2C (SMB0)

The SMBus I/O interface is a two-wire, bi-directional serial bus. The SMBus is compliant with the System Management Bus Specification, version 1.1, and compatible with the I<sup>2</sup>C serial bus.

The SMBus module includes the following features:

- Standard (up to 100 kbps) and Fast (400 kbps) transfer speeds.
- Support for master, slave, and multi-master modes.
- · Hardware synchronization and arbitration for multi-master mode.
- Clock low extending (clock stretching) to interface with faster masters.
- · Hardware support for 7-bit slave and general call address recognition.
- Firmware support for 10-bit slave address decoding.
- Ability to inhibit all slave states.
- · Programmable data setup/hold times.

## 16-bit CRC (CRC0)

The cyclic redundancy check (CRC) module performs a CRC using a 16-bit polynomial. CRC0 accepts a stream of 8-bit data and posts the 16-bit result to an internal register. In addition to using the CRC block for data manipulation, hardware can automatically CRC the flash contents of the device.

The CRC module is designed to provide hardware calculations for flash memory verification and communications protocols. The CRC module supports the standard CCITT-16 16-bit polynomial (0x1021), and includes the following features:

- Support for CCITT-16 polynomial
- · Byte-level bit reversal
- · Automatic CRC of flash contents on one or more 256-byte blocks
- Initial seed selection of 0x0000 or 0xFFFF

### 3.7 Analog

### 12-Bit Analog-to-Digital Converter (ADC0)

The ADC is a successive-approximation-register (SAR) ADC with 12-, 10-, and 8-bit modes, integrated track-and hold and a program-mable window detector. The ADC is fully configurable under software control via several registers. The ADC may be configured to measure different signals using the analog multiplexer. The voltage reference for the ADC is selectable between internal and external reference sources.

- · Up to 16 external inputs.
- · Single-ended 12-bit and 10-bit modes.
- Supports an output update rate of 200 ksps samples per second in 12-bit mode or 800 ksps samples per second in 10-bit mode.
- Operation in low power modes at lower conversion speeds.
- Asynchronous hardware conversion trigger, selectable between software, external I/O and internal timer sources.
- Output data window comparator allows automatic range checking.
- Support for burst mode, which produces one set of accumulated data per conversion-start trigger with programmable power-on settling and tracking time.
- · Conversion complete and window compare interrupts supported.
- · Flexible output data formatting.
- Includes an internal fast-settling reference with two levels (1.65 V and 2.4 V) and support for external reference and signal ground.
- · Integrated temperature sensor.

## Low Current Comparators (CMP0, CMP1)

Analog comparators are used to compare the voltage of two analog inputs, with a digital output indicating which input voltage is higher. External input connections to device I/O pins and internal connections are available through separate multiplexers on the positive and negative inputs. Hysteresis, response time, and current consumption may be programmed to suit the specific needs of the application.

The comparator module includes the following features:

- · Up to 8 external positive inputs.
- Up to 8 external negative inputs.
- · Additional input options:
  - · Internal connection to LDO output.
  - · Direct connection to GND.
- · Synchronous and asynchronous outputs can be routed to pins via crossbar.
- Programmable hysteresis between 0 and ±20 mV
- · Programmable response time.
- · Interrupts generated on rising, falling, or both edges.

#### 3.8 Reset Sources

Reset circuitry allows the controller to be easily placed in a predefined default condition. On entry to this reset state, the following occur:

- · The core halts program execution.
- Module registers are initialized to their defined reset values unless the bits reset only with a power-on reset.
- · External port pins are forced to a known state.
- · Interrupts and timers are disabled.

All registers are reset to the predefined values noted in the register descriptions unless the bits only reset with a power-on reset. The contents of RAM are unaffected during a reset; any previously stored data is preserved as long as power is not lost. The Port I/O latches are reset to 1 in open-drain mode. Weak pullups are enabled during and after the reset. For Supply Monitor and power-on resets, the RSTb pin is driven low until the device exits the reset state. On exit from the reset state, the program counter (PC) is reset, and the system clock defaults to an internal oscillator. The Watchdog Timer is enabled, and program execution begins at location 0x0000.

Reset sources on the device include the following:

- · Power-on reset
- · External reset pin
- · Comparator reset
- Software-triggered reset
- · Supply monitor reset (monitors VDD supply)
- · Watchdog timer reset
- · Missing clock detector reset
- · Flash error reset

### 3.9 Debugging

The EFM8BB1 devices include an on-chip Silicon Labs 2-Wire (C2) debug interface to allow flash programming and in-system debugging with the production part installed in the end application. The C2 interface uses a clock signal (C2CK) and a bi-directional C2 data signal (C2D) to transfer information between the device and a host system. See the C2 Interface Specification for details on the C2 protocol.

#### 3.10 Bootloader

All devices come pre-programmed with a UART bootloader. This bootloader resides in the code security page, which is the last last page of code flash; it can be erased if it is not needed.

The byte before the Lock Byte is the Bootloader Signature Byte. Setting this byte to a value of 0xA5 indicates the presence of the bootloader in the system. Any other value in this location indicates that the bootloader is not present in flash.

When a bootloader is present, the device will jump to the bootloader vector after any reset, allowing the bootloader to run. The bootloader then determines if the device should stay in bootload mode or jump to the reset vector located at 0x0000. When the bootloader is not present, the device will jump to the reset vector of 0x0000 after any reset.

More information about the bootloader protocol and usage can be found in *AN945: EFM8 Factory Bootloader User Guide*. Application notes can be found on the Silicon Labs website (www.silabs.com/8bit-appnotes) or within Simplicity Studio by using the [**Application Notes**] tile.

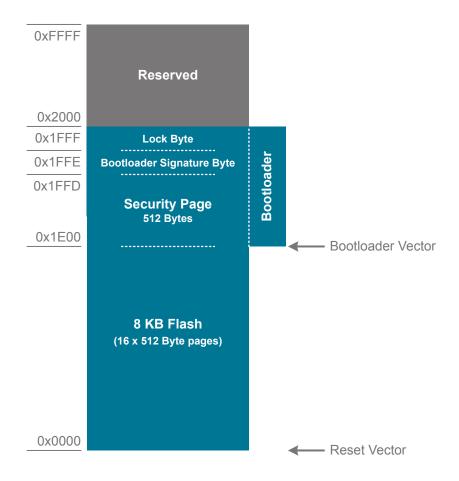


Figure 3.2. Flash Memory Map with Bootloader—8 KB Devices

Table 3.2. Summary of Pins for Bootloader Communication

Bootloader	Pins for Bootload Communication
UART	TX – P0.4
	RX – P0.5

# 4. Electrical Specifications

### 4.1 Electrical Characteristics

All electrical parameters in all tables are specified under the conditions listed in Table 4.1 Recommended Operating Conditions on page 12, unless stated otherwise.

## 4.1.1 Recommended Operating Conditions

**Table 4.1. Recommended Operating Conditions** 

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Operating Supply Voltage on VDD	$V_{DD}$		2.2	_	3.6	V
System Clock Frequency	f <sub>SYSCLK</sub>		0	_	25	MHz
Operating Ambient Temperature	T <sub>A</sub>	G-grade devices	-40	_	85	°C
		I-grade or A-grade devices	-40	_	125	°C

### Note:

- 1. All voltages with respect to GND
- 2. GPIO levels are undefined whenever VDD is less than 1 V.

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
ADC0 Always-on <sup>4</sup>	I <sub>ADC</sub>	800 ksps, 10-bit conversions or	_	845	1200	μA
		200 ksps, 12-bit conversions				
		Normal bias settings				
		V <sub>DD</sub> = 3.0 V				
		250 ksps, 10-bit conversions or	_	425	580	μA
		62.5 ksps 12-bit conversions				
		Low power bias settings				
		V <sub>DD</sub> = 3.0 V				
ADC0 Burst Mode, 10-bit single	I <sub>ADC</sub>	200 ksps, V <sub>DD</sub> = 3.0 V	_	370	_	μA
conversions, external reference		100 ksps, V <sub>DD</sub> = 3.0 V	_	185	_	μA
		10 ksps, V <sub>DD</sub> = 3.0 V	_	19	_	μA
ADC0 Burst Mode, 10-bit single	I <sub>ADC</sub>	200 ksps, V <sub>DD</sub> = 3.0 V	_	490	_	μA
conversions, internal reference, Low power bias settings		100 ksps, V <sub>DD</sub> = 3.0 V	_	245	_	μA
		10 ksps, V <sub>DD</sub> = 3.0 V	_	23	_	μA
ADC0 Burst Mode, 12-bit single	I <sub>ADC</sub>	100 ksps, V <sub>DD</sub> = 3.0 V	_	530	_	μA
conversions, external reference		50 ksps, V <sub>DD</sub> = 3.0 V	_	265	_	μA
		10 ksps, V <sub>DD</sub> = 3.0 V	_	53	_	μA
ADC0 Burst Mode, 12-bit single	I <sub>ADC</sub>	100 ksps, V <sub>DD</sub> = 3.0 V,	_	950	_	μA
conversions, internal reference		Normal bias				
		50 ksps, V <sub>DD</sub> = 3.0 V,	_	420	_	μA
		Low power bias				
		10 ksps, V <sub>DD</sub> = 3.0 V,	_	85	_	μA
		Low power bias				
Internal ADC0 Reference, Always-	I <sub>VREFFS</sub>	Normal Power Mode	_	680	790	μA
on <sup>5</sup>		Low Power Mode	_	160	210	μA
Temperature Sensor	I <sub>TSENSE</sub>		_	75	120	μA
Comparator 0 (CMP0),	I <sub>CMP</sub>	CPMD = 11	_	0.5	_	μA
Comparator 1 (CMP1)		CPMD = 10	_	3	_	μA
		CPMD = 01	_	10	_	μA
		CPMD = 00		25		μA
Voltage Supply Monitor (VMON0)	I <sub>VMON</sub>		_	15	20	μA

# 4.1.4 Flash Memory

Table 4.4. Flash Memory

Parameter	Symbol	Test Condition	Min	Тур	Max	Units
Write Time <sup>1</sup> , <sup>2</sup>	t <sub>WRITE</sub>	One Byte,	19	20	21	μs
		F <sub>SYSCLK</sub> = 24.5 MHz				
Erase Time <sup>1,2</sup>	t <sub>ERASE</sub>	One Page,	5.2	5.35	5.5	ms
		F <sub>SYSCLK</sub> = 24.5 MHz				
V <sub>DD</sub> Voltage During Programming <sup>3</sup>	V <sub>PROG</sub>		2.2	_	3.6	V
Endurance (Write/Erase Cycles)	N <sub>WE</sub>		20k	100k	_	Cycles
CRC Calculation Time	C Calculation Time t <sub>CRC</sub>		_	11	_	μs
		SYSCLK = 24.5 MHz				

### Note:

- 1. Does not include sequencing time before and after the write/erase operation, which may be multiple SYSCLK cycles.
- 2. The internal High-Frequency Oscillator has a programmable output frequency using the HFO0CAL register, which is factory programmed to 24.5 MHz. If user firmware adjusts the oscillator speed, it must be between 22 and 25 MHz during any flash write or erase operation. It is recommended to write the HFO0CAL register back to its reset value when writing or erasing flash.
- 3. Flash can be safely programmed at any voltage above the supply monitor threshold (V<sub>VDDM</sub>).
- 4. Data Retention Information is published in the Quarterly Quality and Reliability Report.

### 4.1.5 Internal Oscillators

Table 4.5. Internal Oscillators

Parameter	Symbol	nbol Test Condition		Тур	Max	Unit				
High Frequency Oscillator 0 (24.5 MHz)										
Oscillator Frequency	f <sub>HFOSC0</sub>	Full Temperature and Supply Range	24	24.5	25	MHz				
Power Supply Sensitivity	PSS <sub>HFOS</sub>	T <sub>A</sub> = 25 °C	_	0.5	_	%/V				
Temperature Sensitivity	TS <sub>HFOSC0</sub>	V <sub>DD</sub> = 3.0 V	_	40	_	ppm/°C				
Low Frequency Oscillator (80 k	Hz)									
Oscillator Frequency	f <sub>LFOSC</sub>	Full Temperature and Supply Range	75	80	85	kHz				
Power Supply Sensitivity	PSS <sub>LFOSC</sub>	T <sub>A</sub> = 25 °C	_	0.05	_	%/V				
Temperature Sensitivity	TS <sub>LFOSC</sub>	V <sub>DD</sub> = 3.0 V	_	65	_	ppm/°C				

# 4.1.6 External Clock Input

# Table 4.6. External Clock Input

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
External Input CMOS Clock	f <sub>CMOS</sub>		0	_	25	MHz
Frequency (at EXTCLK pin)						
External Input CMOS Clock High Time	t <sub>CMOSH</sub>		18	_	_	ns
External Input CMOS Clock Low Time	t <sub>CMOSL</sub>		18	_	_	ns

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Negative Hysteresis	HYS <sub>CP</sub> -	CPHYN = 00	_	-1.5	_	mV
Mode 3 (CPMD = 11)		CPHYN = 01	_	-4	_	mV
		CPHYN = 10	_	-8	_	mV
		CPHYN = 11	_	-16	_	mV
Input Range (CP+ or CP-)	V <sub>IN</sub>		-0.25	_	V <sub>DD</sub> +0.25	V
Input Pin Capacitance	C <sub>CP</sub>		_	7.5	_	pF
Common-Mode Rejection Ratio	CMRR <sub>CP</sub>		_	70	_	dB
Power Supply Rejection Ratio	PSRR <sub>CP</sub>		_	72	_	dB
Input Offset Voltage	V <sub>OFF</sub>	T <sub>A</sub> = 25 °C	-10	0	10	mV
Input Offset Tempco	TC <sub>OFF</sub>		_	3.5	_	μV/°C

## 4.1.12 Port I/O

Table 4.12. Port I/O

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Output High Voltage (Low Drive) <sup>1</sup>	V <sub>OH</sub>	I <sub>OH</sub> = -1 mA	V <sub>DD</sub> – 0.7	_	_	V
Output High Voltage (High Drive) <sup>1</sup>	V <sub>OH</sub>	I <sub>OH</sub> = -3 mA	V <sub>DD</sub> - 0.7	_	_	V
Output Low Voltage (Low Drive) <sup>1</sup>	V <sub>OL</sub>	I <sub>OL</sub> = 1.4 mA	_	_	0.6	V
Output Low Voltage (High Drive) <sup>1</sup>	V <sub>OL</sub>	I <sub>OL</sub> = 8.5 mA	_	_	0.6	V
Output Low Voltage (High Drive) <sup>1</sup>	V <sub>OL</sub>	I <sub>OL</sub> = 10 mA	_	0.25	0.33	V
		-10 °C ≤ T <sub>A</sub> ≤ 60 °C				
		V <sub>DD</sub> = 3.0 V				
		Guaranteed by characterization				
Output Low Voltage (High Drive) <sup>1</sup>	V <sub>OL</sub>	I <sub>OL</sub> = 10 mA	_	0.23	0.31	V
		-10 °C ≤ T <sub>A</sub> ≤ 60 °C				
		V <sub>DD</sub> = 3.6 V				
		Guaranteed by characterization				
Input High Voltage	V <sub>IH</sub>		V <sub>DD</sub> - 0.6	_	_	V
Input Low Voltage	V <sub>IL</sub>		_	_	0.6	V
Pin Capacitance	C <sub>IO</sub>		_	7	_	pF
Weak Pull-Up Current	I <sub>PU</sub>	V <sub>DD</sub> = 3.6	-30	-20	-10	μA
$(V_{IN} = 0 V)$						
Input Leakage (Pullups off or Analog)	I <sub>LK</sub>	GND < V <sub>IN</sub> < V <sub>DD</sub>	-1.1	_	1.1	μA
Input Leakage Current with V <sub>IN</sub> above V <sub>DD</sub>	I <sub>LK</sub>	V <sub>DD</sub> < V <sub>IN</sub> < V <sub>DD</sub> +2.0 V	0	5	150	μA

## Note:

1. See Figure 4.6 Typical  $V_{OH}$  Curves on page 30 and Figure 4.7 Typical  $V_{OL}$  Curves on page 30 for more information.

## 4.4 Typical Performance Curves

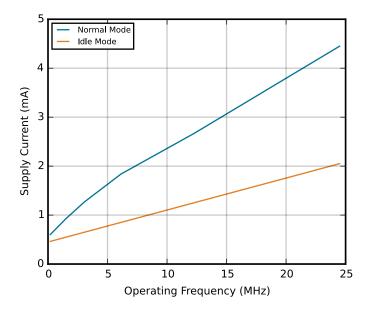


Figure 4.2. Typical Operating Supply Current using HFOSC0

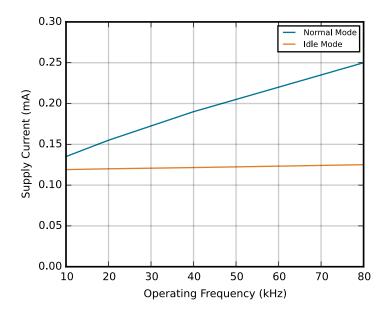


Figure 4.3. Typical Operating Supply Current using LFOSC

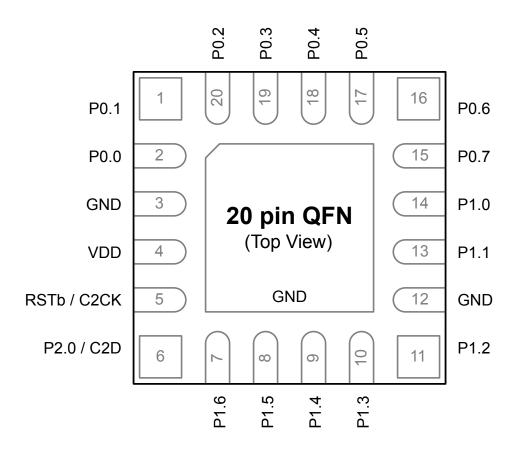


Figure 6.2. EFM8BB1x-QFN20 Pinout

Table 6.2. Pin Definitions for EFM8BB1x-QFN20

Pin	Pin Name	Description	Crossbar Capability	Additional Digital	Analog Functions
Number				Functions	
1	P0.1	Multifunction I/O	Yes	P0MAT.1	ADC0.1
				INT0.1	CMP0P.1
				INT1.1	CMP0N.1
					AGND
2	P0.0	Multifunction I/O	Yes	P0MAT.0	ADC0.0
				INT0.0	CMP0P.0
				INT1.0	CMP0N.0
					VREF

# 7. QSOP24 Package Specifications

## 7.1 QSOP24 Package Dimensions

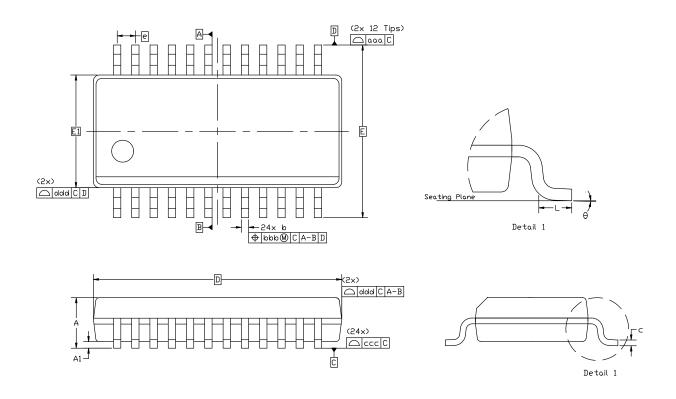


Figure 7.1. QSOP24 Package Drawing

Table 7.1. QSOP24 Package Dimensions

Dimension	Min	Тур	Max	
A	_	_	1.75	
A1	0.10	_	0.25	
b	0.20	_	0.30	
С	0.10	_	0.25	
D	8.65 BSC			
Е	6.00 BSC			
E1	3.90 BSC			
е	0.635 BSC			
L	0.40	_	1.27	
theta	0°	_	8°	

# 8. QFN20 Package Specifications

# 8.1 QFN20 Package Dimensions

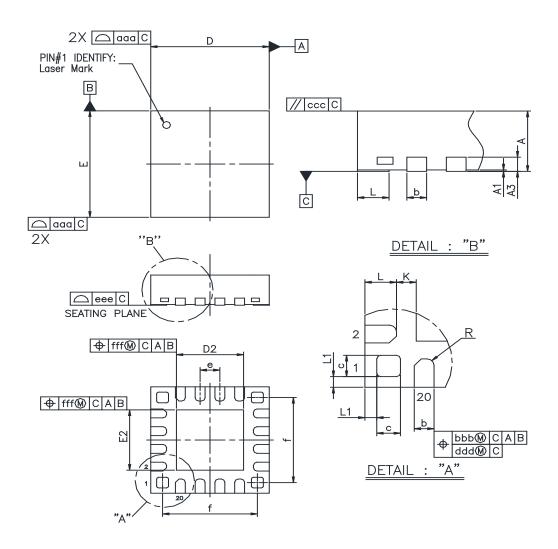


Figure 8.1. QFN20 Package Drawing

Table 8.1. QFN20 Package Dimensions

Dimension	Min	Тур	Max
А	0.70	0.75	0.80
A1	0.00	0.02	0.05
A3	0.20 REF		
b	0.18	0.25	0.30
С	0.25	0.30	0.35
D	3.00 BSC		
D2	1.6	1.70	1.80
е	0.50 BSC		

Dimension	Min	Тур	Max	
Е	3.00 BSC			
E2	1.60	1.70	1.80	
f	2.50 BSC			
L	0.30	0.40	0.50	
К	0.25 REF			
R	0.09	0.125	0.15	
aaa	0.15			
bbb	0.10			
ccc	0.10			
ddd	0.05			
eee	0.08			
fff	0.10			

## Note:

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
- 3. The drawing complies with JEDEC MO-220.
- 4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

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